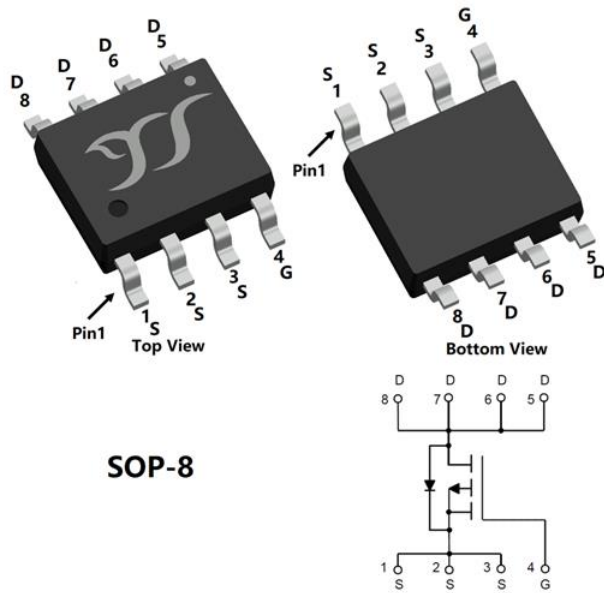


P-Channel Enhancement Mode Field Effect Transistor



SOP-8

Product Summary

- V_{DS} -100V
- I_D -2A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) <200m Ω
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <246m Ω
- 100% EAS Tested
- ESD Level(HBM) Class 1C

General Description

- Extremely low switching loss
- Excellent stability and uniformity
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Power management
- Load switch

Limiting Values

Parameter	Conditions	Symbol	Min	Max	Unit	
Drain-source Voltage		V_{DS}	-	-100	V	
Gate-source Voltage		V_{GS}	-20	20		
Continuous Drain Current (Note 1,2)	Steady-State	I_D	$T_A=25^{\circ}C, V_{GS}=-10V$	-	-2	A
			$T_A=100^{\circ}C, V_{GS}=-10V$	-	-1.26	
Pulsed Drain Current	$T_A=25^{\circ}C, t_p \leq 10\mu s$	I_{DM}	-	-16		
Maximum Body-Diode Continuous Current	$T_A=25^{\circ}C$	I_S	-	-1.5		
Avalanche Energy (non-repetitive)	$T_J=25^{\circ}C, V_G=-10V, R_G=25\Omega, L=0.5mH, I_{AS}=-10A$	EAS	-	25	mJ	
Total Power Dissipation (Note 1,2)	Steady-State	P_D	$T_A=25^{\circ}C$	-	1.78	W
			$T_A=100^{\circ}C$	-	0.71	
Junction and Storage Temperature Range		T_J, T_{STG}	-55	150	$^{\circ}C$	

Thermal Resistance

Parameter	Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	$R_{\theta JA}$	-	70	$^{\circ}C/W$

Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJS200P10AJ	F2	S200P10A	4000	8000	64000	13" reel



YJS200P10AJ

■ Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A, T_j=25^\circ C$	-100	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-100V, V_{GS}=0V, T_j=25^\circ C$	-	-	-1	μA
		$V_{DS}=-100V, V_{GS}=0V, T_j=150^\circ C$	-	-	-100	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V, T_j=25^\circ C$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A, T_j=25^\circ C$	-1	-1.5	-2	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-2A, T_j=25^\circ C$	-	154	200	$m\Omega$
		$V_{GS}=-4.5V, I_D=-1A, T_j=25^\circ C$	-	164	246	$m\Omega$
Diode Forward Voltage	V_{SD}	$I_S=-1A, V_{GS}=0V, T_j=25^\circ C$	-	-0.77	-1.2	V
Gate Resistance	R_G	$f=1MHz, T_j=25^\circ C$	-	20	-	Ω
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=-50V, V_{GS}=0V, f=1MHz, T_j=25^\circ C$	-	1341	-	pF
Output Capacitance	C_{oss}		-	35	-	
Reverse Transfer Capacitance	C_{rss}		-	28	-	
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=-10V, V_{DS}=-50V, I_D=-2A, T_j=25^\circ C$	-	25.5	-	nC
Gate-Source Charge	Q_{gs}		-	2.6	-	
Gate-Drain Charge	Q_{gd}		-	3.1	-	
Reverse Recovery Charge	Q_{rr}	$I_F=-2A, di/dt=100A/\mu s, V_{GS}=0V, V_R=-50V, T_j=25^\circ C$	-	32	-	nC
Reverse Recovery Time	t_{rr}		-	24	-	ns
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=-10V, V_{DS}=-50V, I_D=-2A, R_{GEN}=3\Omega, T_j=25^\circ C$	-	5.9	-	ns
Turn-on Rise Time	t_r		-	3.6	-	
Turn-off Delay Time	$t_{D(off)}$		-	140	-	
Turn-off Fall Time	t_f		-	55	-	

Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of $R_{\theta JA}$ is measured with the device mounted on the 80mm*80mm*1.1mm single layer FR-4 PCB board with 1 in² pad of 2oz. Copper, in the still air environment with $T_A=25^\circ C$. The maximum allowed junction temperature of 150 $^\circ C$. The value in any given application depends on the user's specific board design.



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Typical Electrical and Thermal Characteristics Diagrams

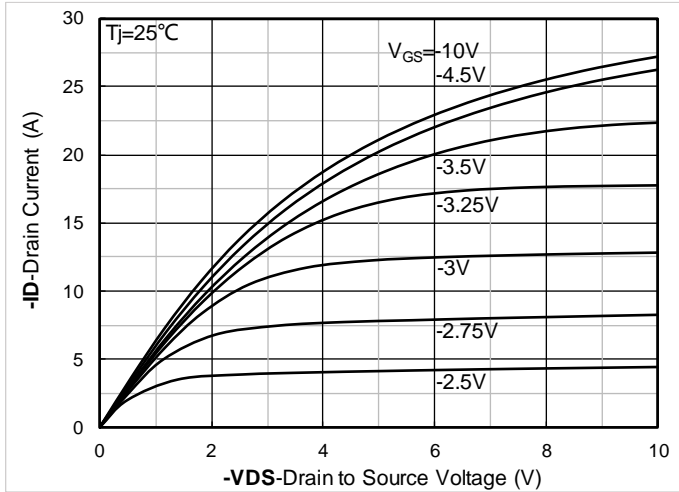


Figure 1. Output Characteristics; typical values

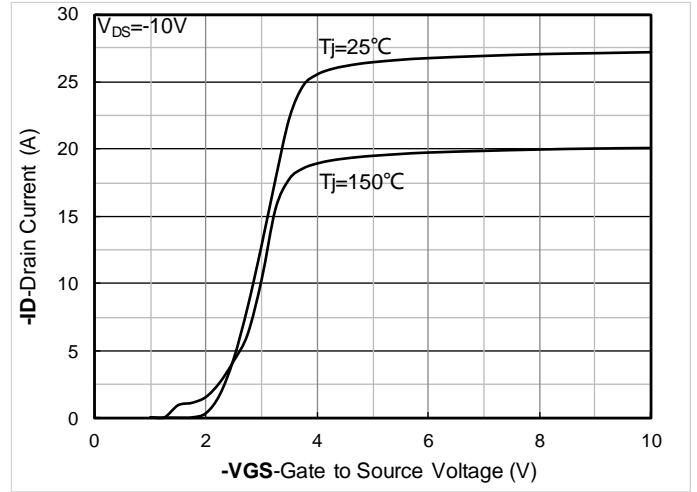


Figure 2. Transfer Characteristics; typical values

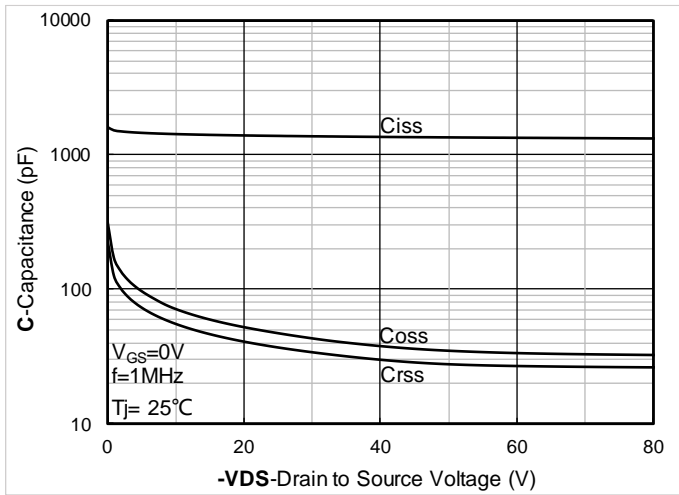


Figure 3. Capacitance Characteristics; typical values

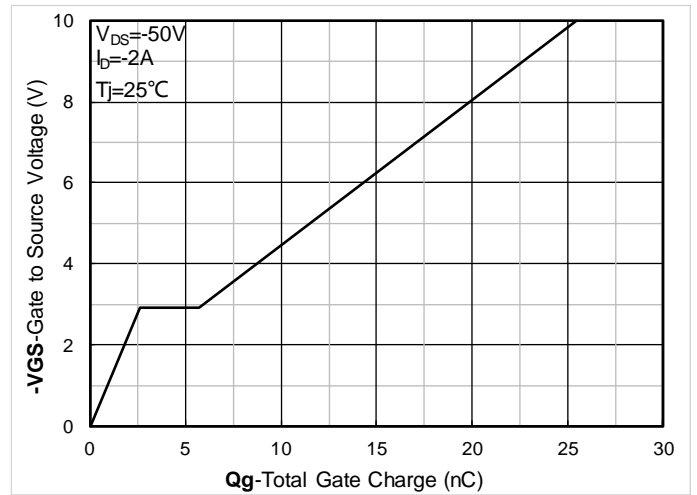


Figure 4. Gate Charge; typical values

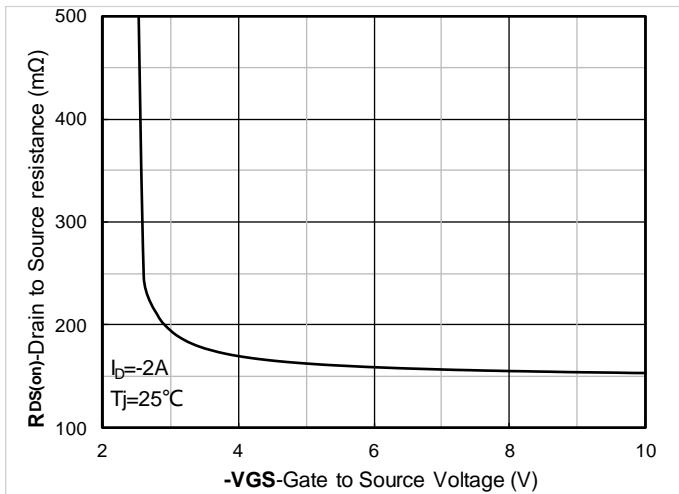


Figure 5. On-Resistance vs. Gate to Source Voltage; typical values

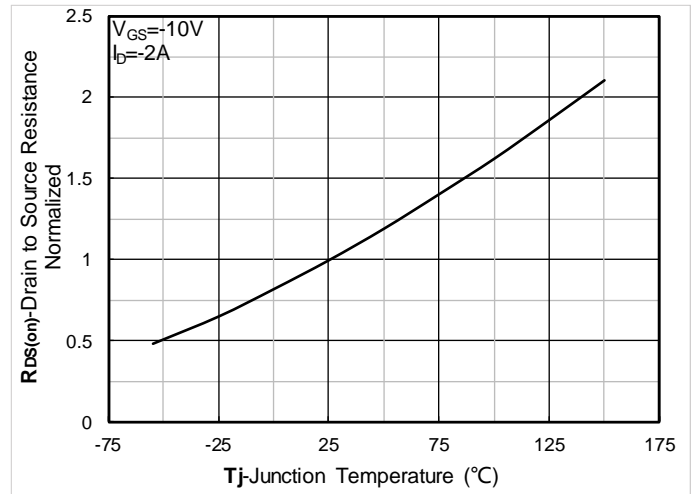


Figure 6. Normalized On-Resistance



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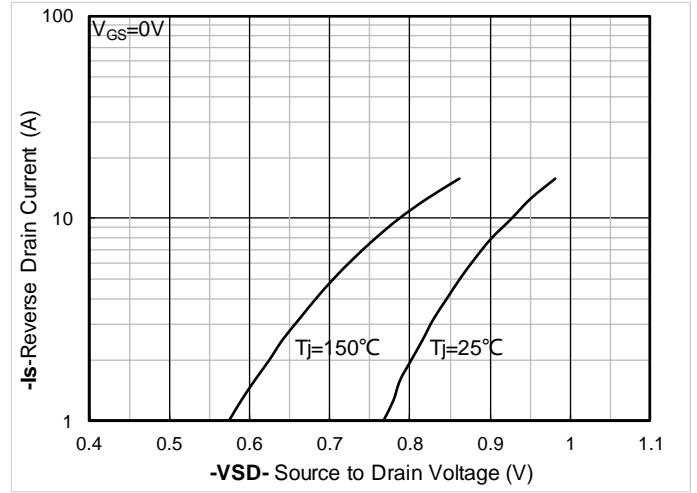
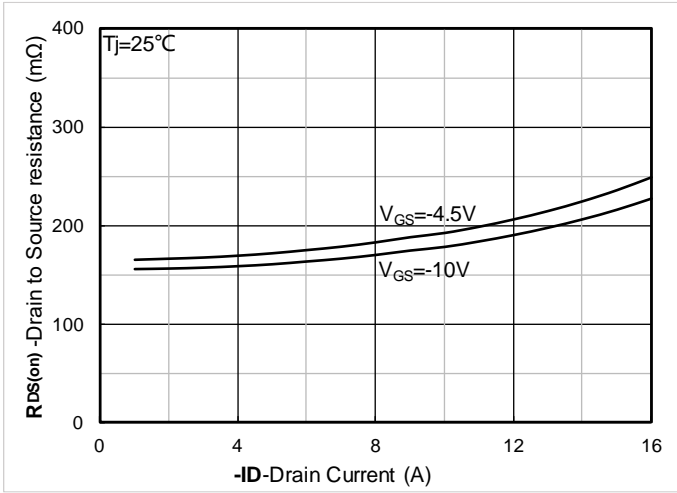


Figure 7. RDS(on) vs. Drain Current; typical values

Figure 8. Forward characteristics of reverse diode; typical values

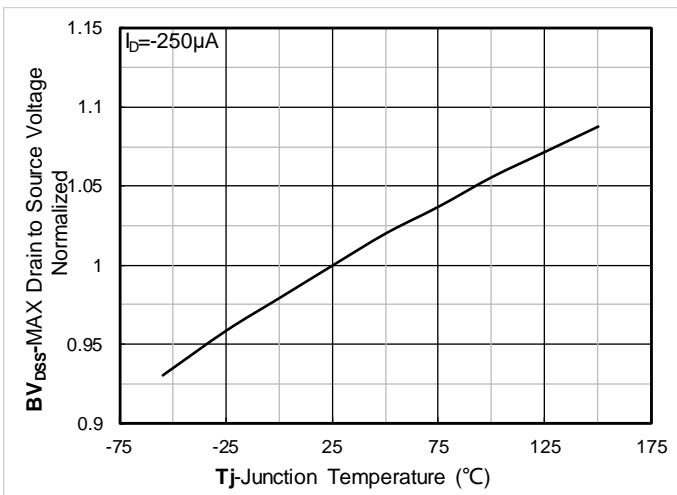


Figure 9. Normalized breakdown voltage

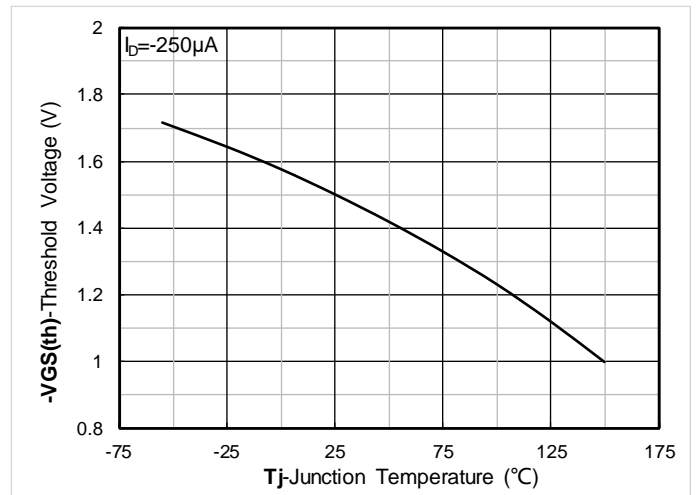


Figure 10. Gate Threshold voltage; typical values

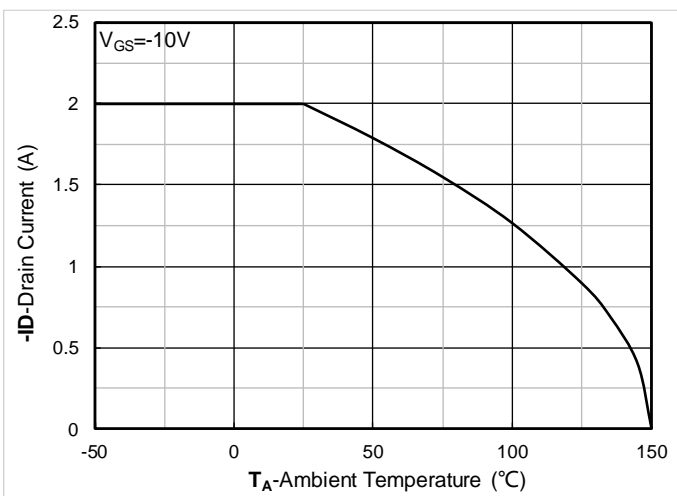


Figure 11. Current dissipation

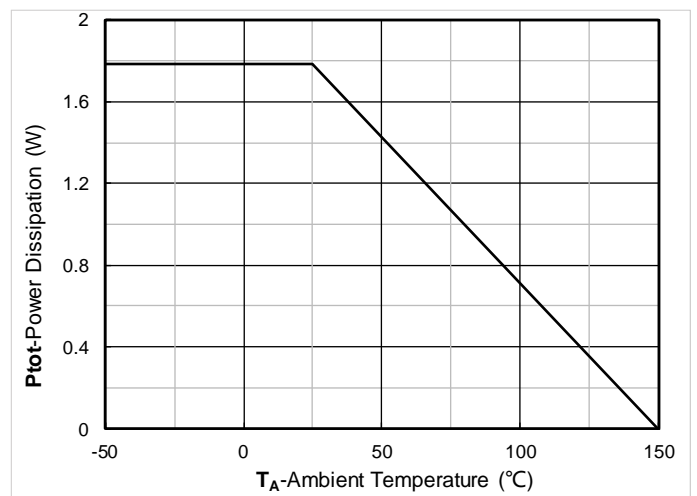


Figure 12. Power dissipation



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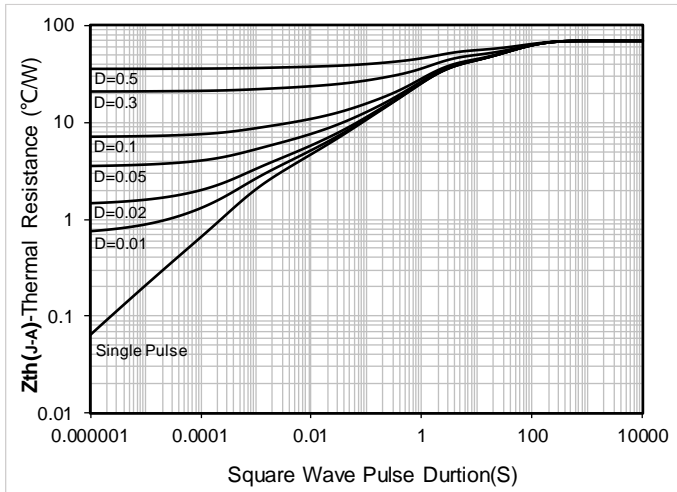


Figure 13. Maximum Transient Thermal Impedance

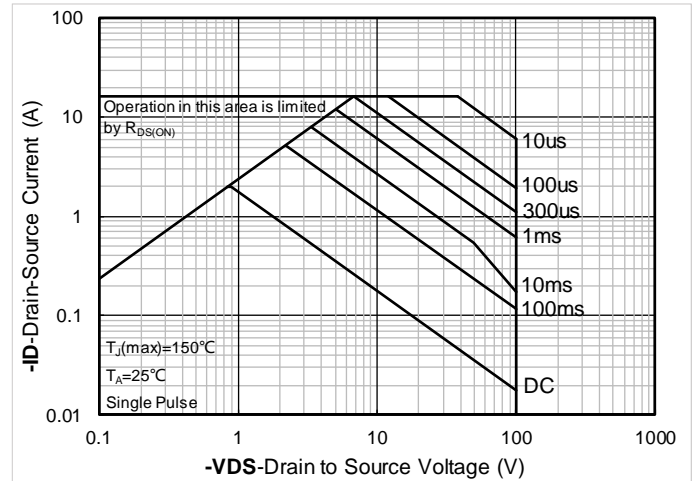
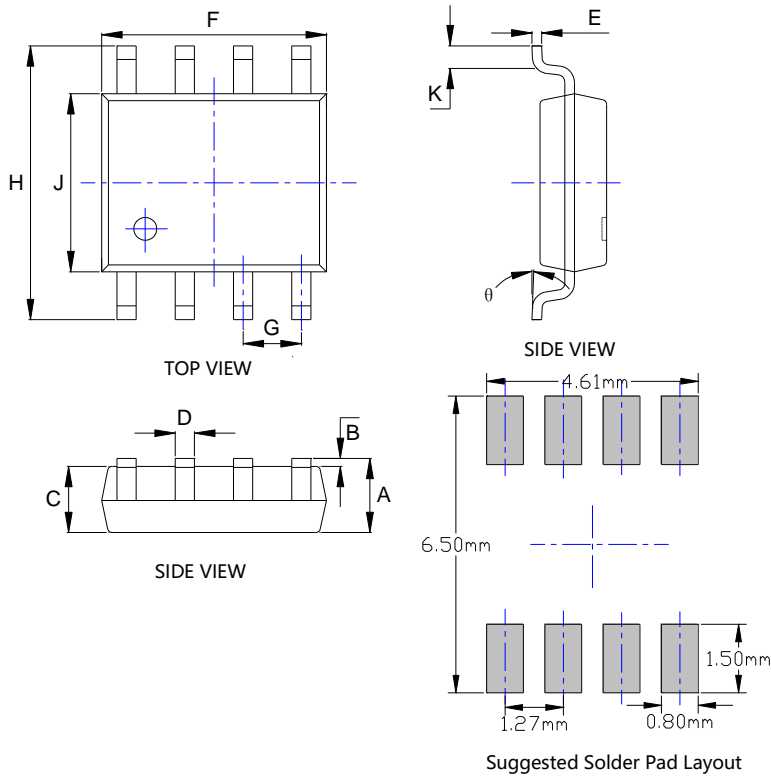


Figure 14. Safe Operation Area



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■ SOP-8 Package information

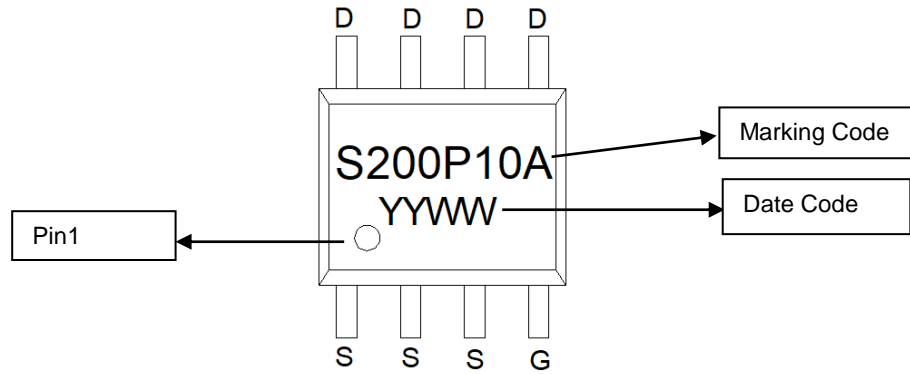


SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.053	0.069	1.350	1.750
B	0.004	0.010	0.100	0.250
C	0.053	0.061	1.350	1.550
D	0.013	0.020	0.330	0.510
E	0.007	0.010	0.170	0.250
F	0.189	0.197	4.800	5.000
G	0.050BSC		1.270BSC	
H	0.228	0.244	5.800	6.200
J	0.150	0.157	3.800	4.000
K	0.016	0.050	0.400	1.270
θ	0°	8°	0°	8°

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

■ Marking Information



Note:

1. All marking is at middle of the product body
2. All marking is in laser printing
3. S200P10A is marking code, YYWW is date code, "YY" is year, "WW" is week
4. Body color: Black



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